NSN 5961-00-116-9363

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-116-9363 **Inclosure Material:** Metal **Overall Length:** 0.405 inches **Overall Width:** 0.437 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 150.0 working peak reverse voltage **Current Rating Per Characteristic:** 12.00 amperes average forward current averaged over a full 60-hz cycle **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud **Specification Or Standard:** 1n1201ra type Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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